NSN 5962-01-461-3769

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-40.0/+85.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15i
Features Provided:
Electrostatic sensitive
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl
Voltage Rating And Type Per Characteristic:
-0.6 volts input and 6.25 volts input
-0.6 volts input and 6.25 volts input Memory Device Type:
Memory Device Type:
Memory Device Type: Eeprom
Memory Device Type: Eeprom Terminal Type And Quantity:
Memory Device Type: Eeprom Terminal Type And Quantity: 32 flat leads
Memory Device Type: Eeprom Terminal Type And Quantity: 32 flat leads Shelf Life:
Memory Device Type: Eeprom Terminal Type And Quantity: 32 flat leads Shelf Life: N/a
Memory Device Type: Eeprom Terminal Type And Quantity: 32 flat leads Shelf Life: N/a Unit Of Measure:
Memory Device Type: Eeprom Terminal Type And Quantity: 32 flat leads Shelf Life: N/a Unit Of Measure:
Memory Device Type: Eeprom Terminal Type And Quantity: 32 flat leads Shelf Life: N/a Unit Of Measure: Demilitarization:
Memory Device Type: Eeprom Terminal Type And Quantity: 32 flat leads Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli
Memory Device Type: Eeprom Terminal Type And Quantity: 32 flat leads Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli Fiig:
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